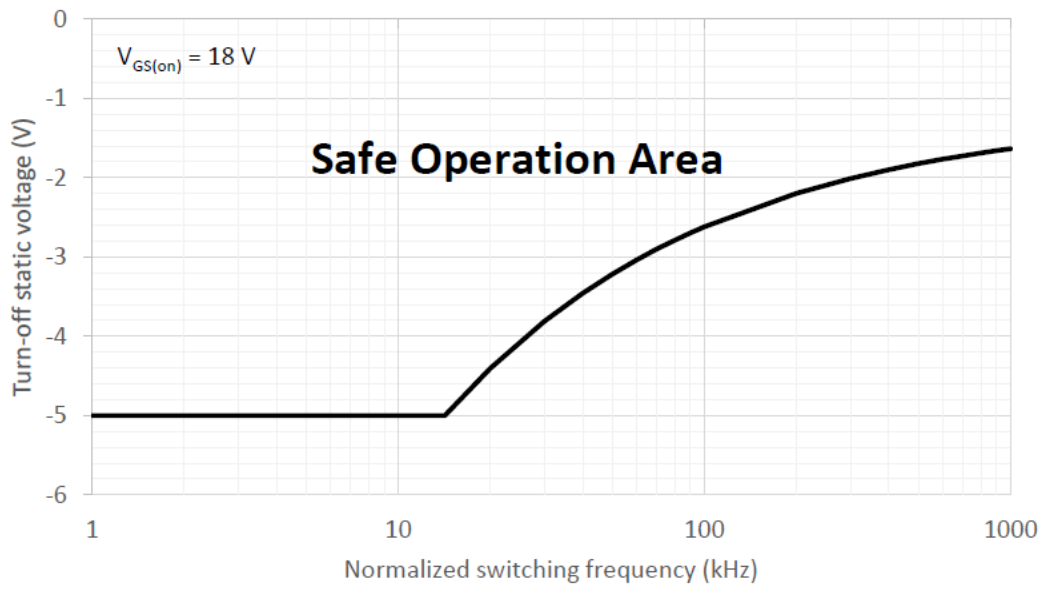
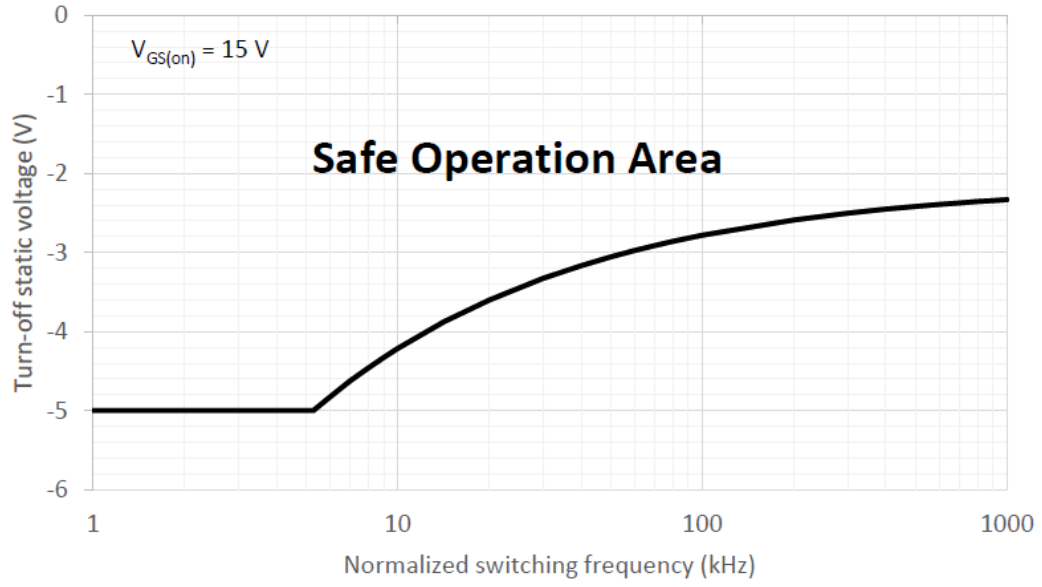


SiC MOSFET



$R_{DS(on)}$ increase v.s. T_j

